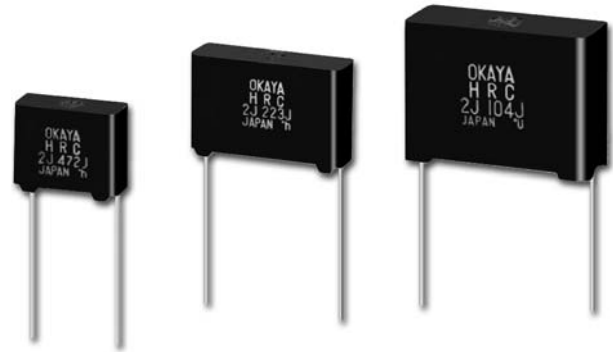


Features

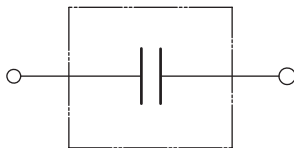
- Best for high frequency and high current.
- Current withstand capability is more than twice of the previous model (two times more than C7NP).

Applications

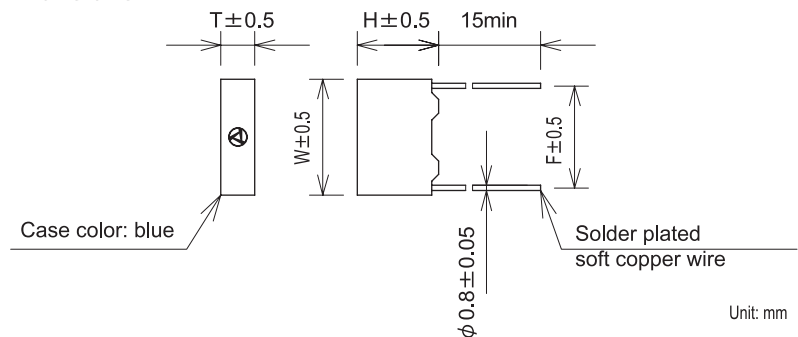
- High frequency resonant circuit, Resonant inverter circuit, Snubber circuit and Protection of semiconductors.



Circuit



Dimensions



Electrical Specifications

Operating Temperature: -40 ~ +85°C

Capacitance		2 J (630WV)				3 B (1250WV)				Dissipation factor	Test voltage	Insulation resistance						
PART NO.	W·V μF	W	T	H	F	W	T	H	F									
102	0.001	17.0	5.0	12.0	15.0	17.0	5.0	12.0	15.0	0.001Max. (at 1000 ±100Hz)	Rated Voltage x 1.75 (2~5sec)	50kMΩ Min. at 20°C 100Vdc						
152	0.0015		5.0	12.0			5.0	12.0										
222	0.0022		5.5	12.5			5.5	12.5										
332	0.0033		6.5	13.5			6.5	13.5										
472	0.0047						8.0	15.0					8.0	15.0				
682	0.0068		8.0	15.0			25.0	6.5					16.0	22.5	25.0	10.0	19.5	22.5
103	0.01																	
153	0.015		25.0	10.0			19.5	22.5										
223	0.022	25.0	6.5	16.0	22.5	25.0	10.0	19.5	22.5									
333	0.033	25.0	8.0	17.5	22.5	30.0	11.0	22.0	27.5									
473	0.047	25.0	10.0	19.5	22.5	30.0	13.5	24.5	27.5									
683	0.068	30.0	11.0	22.0	27.5	30.5	16.0	28.0	27.5									
104	0.1	30.0	11.0	22.0	27.5	36.0	22.0	33.5	32.5									

● Model Numbering System

